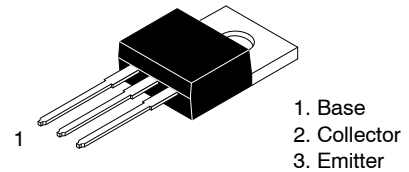


# NPN Silicon Transistor

## KSC5027

### High Voltage and High Reliability

- High Speed Switching
- Wide SOA



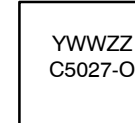
TO-220-3LD  
CASE 340AT

### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted.)

| Symbol           | Parameter                                     | Ratings   | Unit |
|------------------|-----------------------------------------------|-----------|------|
| V <sub>CBO</sub> | Collector–Base Voltage                        | 1100      | V    |
| V <sub>CEO</sub> | Collector–Emitter Voltage                     | 800       | V    |
| V <sub>EBO</sub> | Emitter–Base Voltage                          | 7         | V    |
| I <sub>C</sub>   | Collector Current (DC)                        | 3         | A    |
| I <sub>CP</sub>  | Collector Current (Pulse)                     | 10        | A    |
| I <sub>B</sub>   | Base Current                                  | 1.5       | A    |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> = 25°C) | 50        | W    |
| T <sub>J</sub>   | Junction Temperature                          | 150       | °C   |
| T <sub>STG</sub> | Storage Temperature                           | –55 ~ 150 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### MARKING DIAGRAM



&3 = Date Code (Year & Week)  
 &K = Lot Run Traceability Code  
 C5027 = Specific Device Code  
 O = h<sub>FE</sub> Grade

### ORDERING INFORMATION

| Device     | Package                                 | Shipping             |
|------------|-----------------------------------------|----------------------|
| KSC5027OTU | TO-220-3LD<br>(Pb-Free,<br>Halide Free) | 1000 Units /<br>Tube |

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

| Symbol                               | Parameter                            | Conditions                                                                                                              | Min     | Typ | Max | Unit |
|--------------------------------------|--------------------------------------|-------------------------------------------------------------------------------------------------------------------------|---------|-----|-----|------|
| BV <sub>CBO</sub>                    | Collector–Base Breakdown Voltage     | I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0                                                                               | 1100    | –   | –   | V    |
| BV <sub>CEO</sub>                    | Collector–Emitter Breakdown Voltage  | I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0                                                                               | 800     | –   | –   | V    |
| BV <sub>EBO</sub>                    | Emitter–Base Breakdown Voltage       | I <sub>E</sub> = 1 mA, I <sub>C</sub> = 0                                                                               | 7       | –   | –   | V    |
| V <sub>CES(sus)</sub> 1              | Collector–Emitter Sustaining Voltage | I <sub>C</sub> = 1.5 A, I <sub>B1</sub> = –I <sub>B2</sub> = 0.3 A,<br>L = 2 mH, Clamped                                | 800     | –   | –   | V    |
| I <sub>CBO</sub>                     | Collector Cut-off Current            | V <sub>CB</sub> = 800 V, I <sub>E</sub> = 0                                                                             | –       | –   | 10  | μA   |
| I <sub>EBO</sub>                     | Emitter Cut-off Current              | V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0                                                                               | –       | –   | 10  | μA   |
| h <sub>FE1</sub><br>h <sub>FE2</sub> | DC Current Gain                      | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.2 A<br>V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A                            | 10<br>8 | –   | 40  |      |
| V <sub>CE(sat)</sub>                 | Collector–Emitter Saturation Voltage | I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 0.3 A                                                                          | –       | –   | 2   | V    |
| V <sub>BE(sat)</sub>                 | Base–Emitter Saturation Voltage      | I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 0.3 A                                                                          | –       | –   | 1.5 | V    |
| C <sub>ob</sub>                      | Output Capacitance                   | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz                                                                   | –       | 60  | –   | μs   |
| f <sub>T</sub>                       | Current Gain Bandwidth Product       | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.2 A                                                                          | –       | 15  | –   | MHz  |
| t <sub>ON</sub>                      | Turn On Time                         | V <sub>CC</sub> = 400 V, I <sub>C</sub> = 5 A,<br>I <sub>B1</sub> = –2.5, I <sub>B2</sub> = 2 A, R <sub>L</sub> = 200 Ω | –       | –   | 0.5 | μs   |
| t <sub>STG</sub>                     | Storage Time                         |                                                                                                                         | –       | –   | 3   | μs   |
| t <sub>F</sub>                       | Fall Time                            |                                                                                                                         | –       | –   | 0.3 | μs   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### h<sub>FE</sub> Classification

| Classification   | N       | R       | O       |
|------------------|---------|---------|---------|
| H <sub>FE1</sub> | 10 ~ 20 | 15 ~ 30 | 20 ~ 40 |

## TYPICAL CHARACTERISTICS

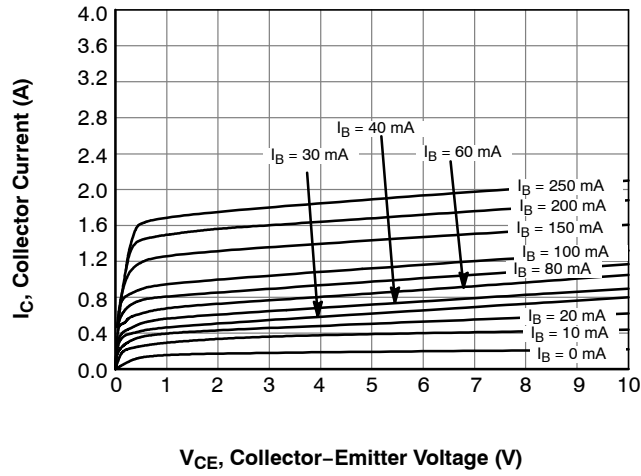


Figure 1. Static Characteristic

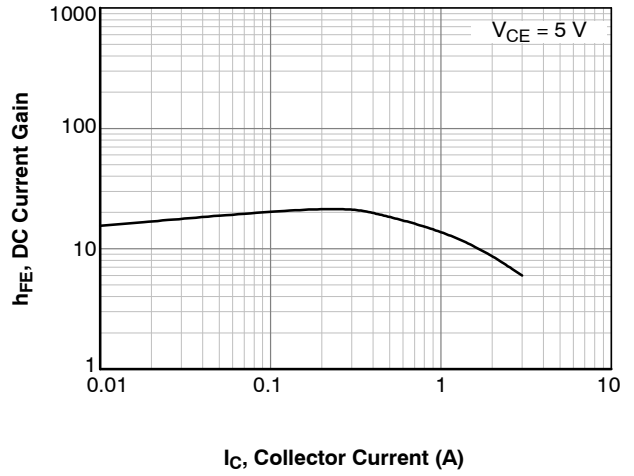


Figure 2. DC Current Gain

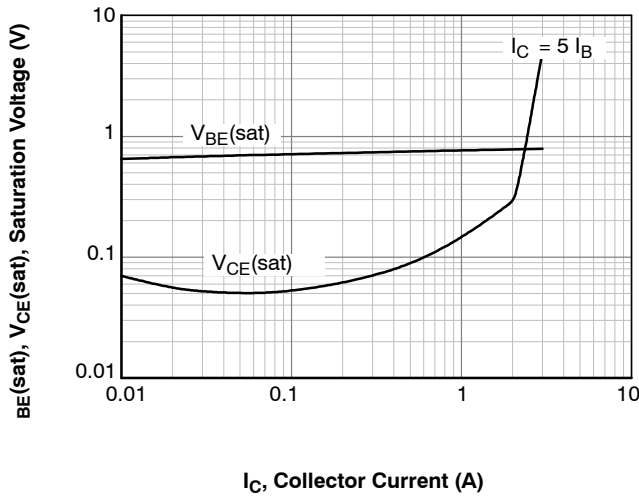
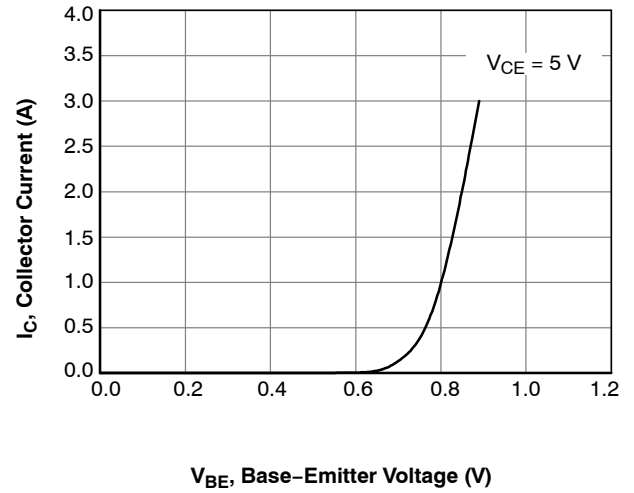
Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

Figure 4. Base-Emitter On Voltage

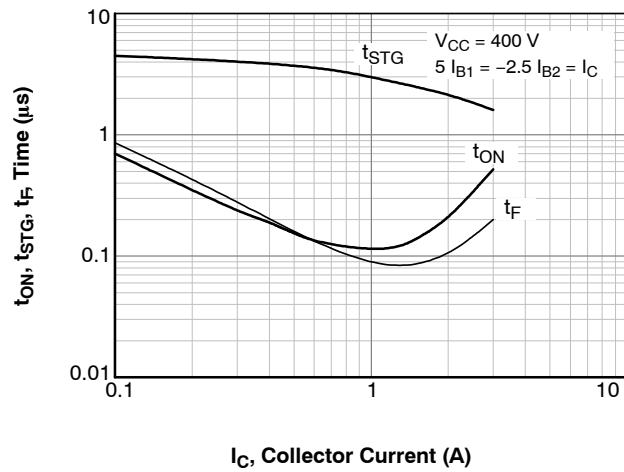


Figure 5. Switching Time

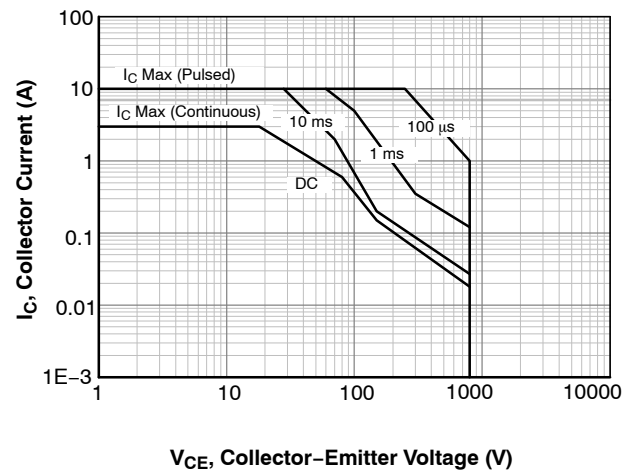


Figure 6. Safe Operating Area

TYPICAL CHARACTERISTICS (Continued)

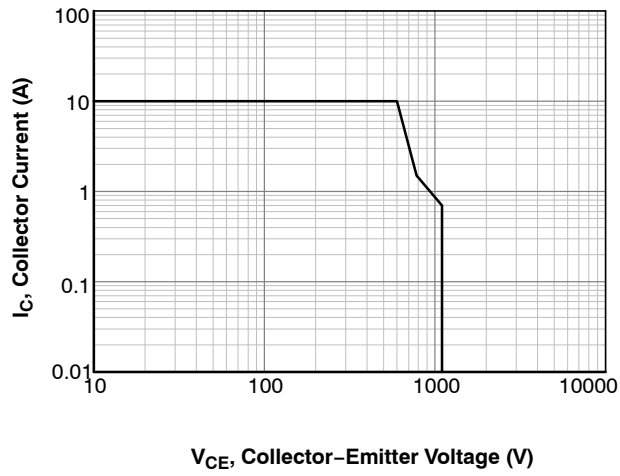


Figure 7. Reverse Bias Operating Areas

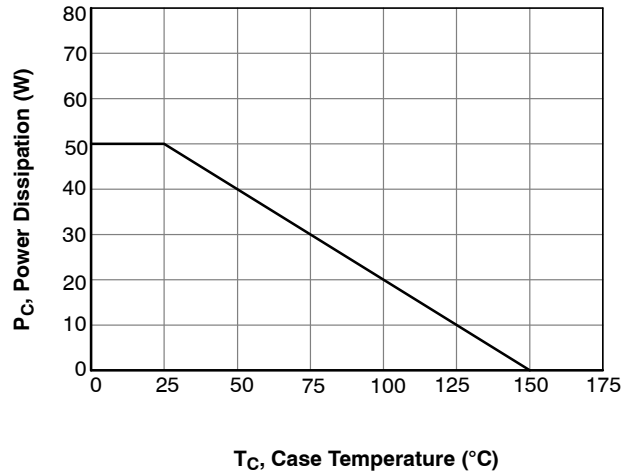
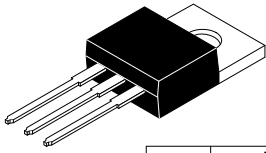


Figure 8. Power Derating



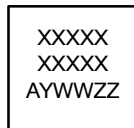
TO-220-3LD  
CASE 340AT  
ISSUE B

DATE 08 AUG 2022

| DIM | MILLIMETERS  |      |       |
|-----|--------------|------|-------|
|     | MIN.         | NOM. | MAX.  |
| A   | 4.00         | --   | 4.70  |
| A1  | SEE NOTE "F" |      |       |
| A2  | 2.10         | --   | 2.85  |
| b   | 0.55         | --   | 1.00  |
| b2  | 1.10         | --   | 1.62  |
| b4  | 1.42         | --   | 1.62  |
| c   | 0.36         | --   | 0.60  |
| D   | 13.90        | --   | 16.30 |
| D1  | 8.13         | --   | 9.40  |
| D2  | 11.50        | --   | 14.30 |
| D3  | 15.42        | --   | 16.51 |
| E   | 9.65         | --   | 10.67 |
| E1  | 7.59         | --   | 8.65  |
| e   | 2.40         | --   | 2.67  |
| H1  | 6.06         | --   | 6.69  |
| L   | 12.70        | --   | 14.04 |
| L1  | 2.70         | --   | 4.10  |
| P   | 3.50         | --   | 4.00  |
| Q   | 2.50         | --   | 3.40  |
| z   | 2.13 REF     |      |       |
| z1  | 2.06 REF     |      |       |
| θ   | 3°           | --   | 5°    |

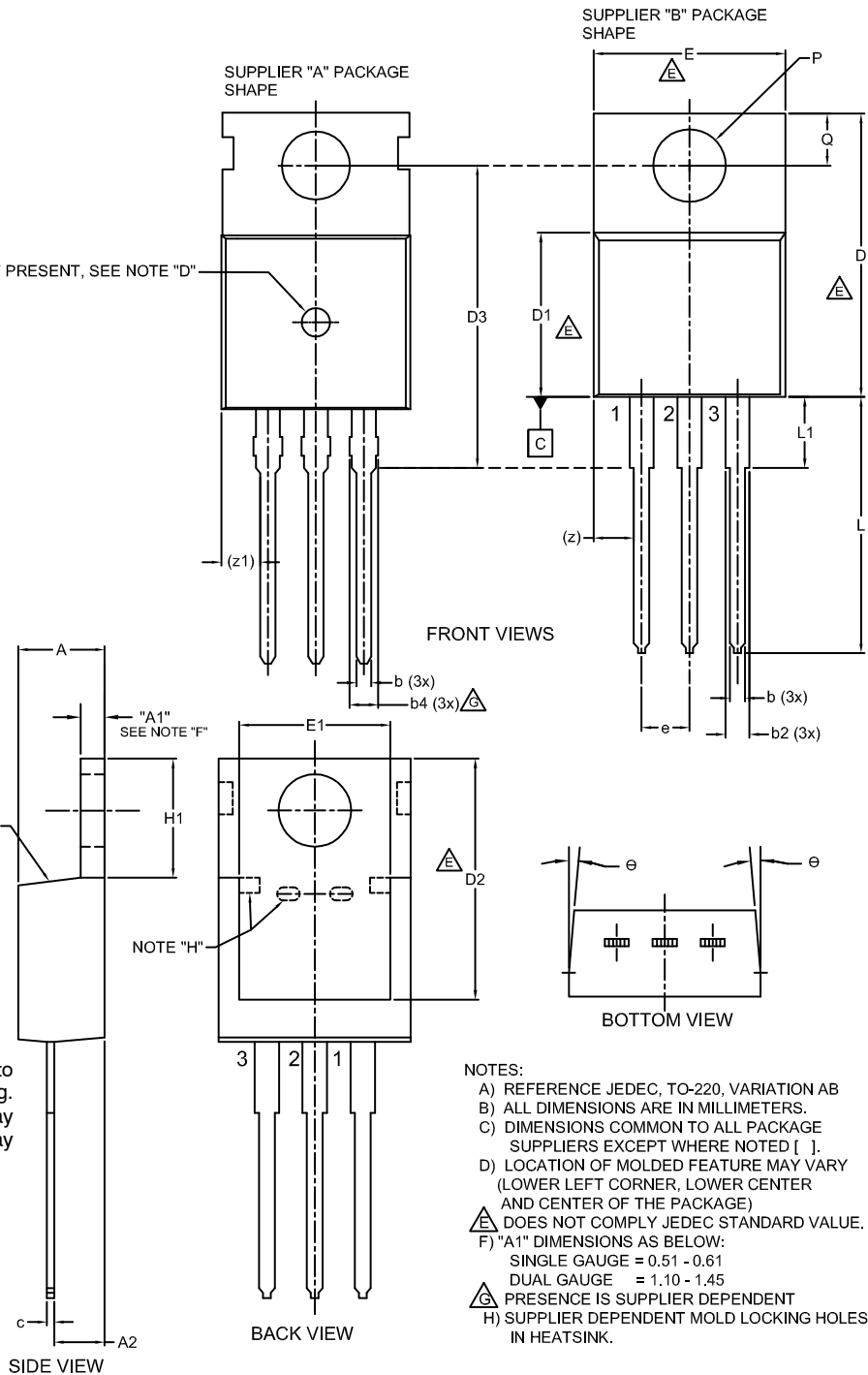
IF PRESENT, SEE NOTE "D"

GENERIC  
MARKING DIAGRAM\*



XXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
ZZ = Assembly Lot Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



NOTES:

- A) REFERENCE JEDEC, TO-220, VARIATION AB
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS COMMON TO ALL PACKAGE SUPPLIERS EXCEPT WHERE NOTED [ ].
- D) LOCATION OF MOLDED FEATURE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
- △ DOES NOT COMPLY JEDEC STANDARD VALUE.
- F) "A1" DIMENSIONS AS BELOW:  
SINGLE GAUGE = 0.51 - 0.61  
DUAL GAUGE = 1.10 - 1.45
- △ PRESENCE IS SUPPLIER DEPENDENT
- H) SUPPLIER DEPENDENT MOLD LOCKING HOLES IN HEATSINK.

|                  |             |                                                                                                                                                                                     |
|------------------|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DOCUMENT NUMBER: | 98AON13818G | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION:     | TO-220-3LD  | PAGE 1 OF 1                                                                                                                                                                         |

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at  
[www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)